imall

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74AHC594

8-BIT SHIFT REGISTER WITH 8-BIT OUTPUT REGISTER

Description

The 74AHC594 is an advanced high speed CMOS device.

An eight bit shift register accepts data from the serial input (DS) on each positive transition of the shift register clock (SHCP). When asserted low the shift regisister reset function (\overline{SHR}) sets all shift register values to zero and is independent of all clocks. Also when asserted low the storage register reset function (\overline{STR}) sets all shift register values to zero and is independent of all clocks.

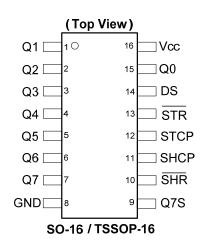
Data from the input serial shift register is placed in the output register with a rising pulse on the storages resister clock (STCP). The storage resister includes output Q7S which is used for cascading information between devices. As the information moves into the storage register, it is asserted on the push-pull outputs Q0-Q7.

All registers capture data on rising edge and change output on the falling edge. If both clocks are connected together, the input shift register is always one clock cycle ahead of the output register.

Features

- Wide Supply Voltage Range from 2.0V to 5.5V
- Sinks or sources 8mA at V_{CC} = 4.5V
- CMOS low power consumption
- Schmitt Trigger Action at All Inputs
- Inputs accept up to 5.5V
- ESD Protection Tested per JESD 22
 - Exceeds 200-V Machine Model (A115-A)
 - Exceeds 2000-V Human Body Model (A114-A)
 - Exceeds 1000-V Charged Device Model (C101C)
- Latch-Up Exceeds 250mA per JESD 78, Class II
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Pin Assignments



Applications

- General Purpose Logic
- Serial to Parallel Data conversion
- Capture and hold data for extended periods of time.
- Allow simple serial bit streams from a microcontroller to control as many peripheral lines as needed
- Wide array of products such as:
 - Computer Peripherals
 - Appliances
 - Industrial Control

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

- 2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

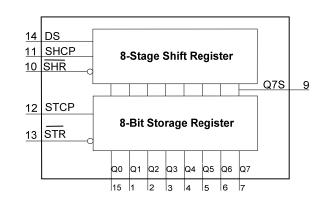
Click here for ordering information, located at the end of datasheet



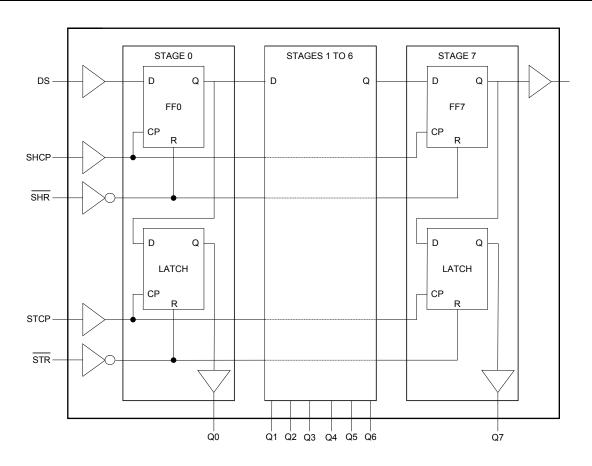
Pin Descriptions

	-	
Pin Number	Pin Name	Functions
1	Q1	Parallel Data Output 1
2	Q2	Parallel Data Output 2
3	Q3	Parallel Data Output 3
4	Q4	Parallel Data Output 4
5	Q5	Parallel Data Output 5
6	Q6	Parallel Data Output 6
7	Q7	Parallel Data Output 7
8	GND	Ground
9	Q7S	Serial Data Output
10	SHR	Shift Register Reset active low
11	SHCP	Shift Register Clock Input
12	STCP	Storage Register Clock Input
13	STR	Storage Register Reset active low
14	DS	Serial Data input
15	Q0	Parallel Data Output 0
16	Vcc	Supply Voltage

Functional Diagram



Logic Diagram





Functional Description and Timing Diagram

	Control			Input	Output		Emotion
SHR	STR	SHCP	STCP	DS	Q7S	Qn	Function
L	Х	Х	Х	Х	L	NC	Clear Shift Register
Х	L	Х	Х	Х	NC	L	Clear Storage Register
Н	Х	1	L	H or L	Q6S	NC	Loads DS into shift register stage 0. All Q_S shifted
Н	Н	Х	↑	Х	NC	Qs	Contents of shift register moved to starge register all $Q_S \rightarrow Q_N$
Н	Н	1	1	H or L	Q6S	QnS	Shift Register one pulse count ahead of storage register.

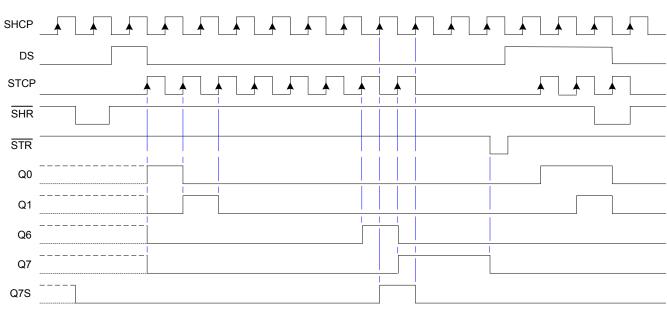
H=HIGH voltage state

L=LOW voltage state

↑=LOW to HIGH transition

X= don't care - high or low (not floating)

NC= No change



Absolute Maximum Ratings (Note 4) (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	kV
ESD CDM	Charged Device Model ESD Protection	1	kV
ESD MM	Machine Model ESD Protection	200	V
Vcc	Supply Voltage Range	-0.5 to +7.0	V
VI	Input Voltage Range	-0.5 to +7.0	V
Vo	Voltage applied to output in high or low state	-0.3 to V _{CC} +0.5	V
I _{IK}	Input Clamp Current VI< -0.5V	-20	mA
loк	Output Clamp Current V _O <-0.5V	-20	mA
I _{OK}	Output Clamp Current V _O > V _{CC} +0.5V	20	mA
lo	Continuous output current	±25	mA
Icc	Continuous current through Vcc	75	mA
I _{GND}	Continuous current through GND	-75	mA
TJ	Operating Junction Temperature	-40 to +150	°C
T _{STG}	Storage Temperature	-65 to +150	°C
P _{TOT}	Total Power Dissipation	500	mW

Notes: 4. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.



Recommended Operating Conditions (Note 5) (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Max	Unit
Vcc	Supply Voltage	_	2.0	5.5	V
VI	Input Voltage	_	0	5.5	V
Vo	Output Voltage	_	0	V _{CC}	V
A 1 / A) /	Innut transition Disc on Fall Date	V _{CC} = 3.0V to 3.6V	-	100	
Δt/ΔV	Input transition Rise or Fall Rate	V _{CC} = 4.5V to 5.5V	_	20	ns/V
T _A	Operating Free-Air Temperature	-	-40	+125	°C

Note: 5. Unused inputs should be held at V_{CC} or Ground.

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Cumhal	Devementer	Test Conditions	M	ΤA	= +25°	С	T _A = -40°C	to +85°C	T _A = -40°C	C to +125°C	Unit
Symbol	Parameter	Test Conditions	V _{CC}	Min	Тур	Max	Min	Max	Min	Max	Unit
		-	2.0V	1.5	-	-	1.5	-	1.5	-	
VIH	High-Level Input Voltage	-	3.0V	2.1	-	-	2.1	-	2.1	-	V
	input voltage	-	5.5V	3.85	-	-	3.85	-	3.85	-	
		-	2.0V	-	-	0.5	-	0.5	-	0.5	
VIL	Low-Level Input Voltage	-	3.0V	-	-	0.9	-	0.9	-	0.9	V
	input voltago	_	5.5V	-	-	1.65	-	1.65	-	1.65	
		I _{OH} = -50μA	2.0V	1.9	2.0	-	1.9	-	1.9	-	
	High-Level Output Voltage	I _{OH} = -50μA	3.0V	2.9	3.0	-	2.9	-	2.9	-	V
VOH		I _{OH} = -50µA	4.5V	4.4	4.5	-	4.4	-	4.4	-	
		I _{OH} = -4mA	3.0V	2.58	-	-	2.48	-	2.40	-	
		I _{OH} = -8mA	4.5V	3.94	-	-	3.80	-	3.70	_	
		I _{OL} = 50μA	2.0V	-	0	0.1	_	0.1	_	0.1	
		I _{OL} = 50μA	3.0V	-	0	0.1	-	0.1	-	0.1	
V _{OL}	Low-Level Output Voltage	I _{OL} = 50μA	4.5V	-	0	0.1	-	0.1	-	0.1	V
	Output Voltage	I _{OL} = 4mA	3.0V	-	-	0.36	-	0.44	-	0.55	
		I _{OL} = 8mA	4.5V	-	-	0.36	-	0.44	-	0.55	
lı	Input Current	V_{I} = GND or 5.5V	5.5V	-	0.01	± 0.1	-	± 1	-	± 2	μA
Icc	Supply Current	$V_{I} = GND \text{ or } V_{CC}$ $I_{O} = 0$	5.5V	_	_	4	_	40	_	80	μA
Ci	Input Capacitance	$V_i = V_{CC}$ or GND	5.5V	_	3.5	10	_	10	-	10	pF



Switching Characteristics

Symbol /	Dina	To al Que dillions	v	Т	A = +25°	С	-40°C t	o +85°C	-40°C to) +125°C	
Parameter	Pins	Test Conditions	V _{CC}	Min	Тур	Max	Min	Max	Min	Max	Unit
f _{MAX}	SHCP or		3.0V to 3.6V	80	125	-	70	-	65	-	
Maximum Frequency	STCP	Figure1	4.5V to 5.5V	90	70	-	80	-	70	-	MHz
	SHCP and		3.0V to 3.6V	6.0	-	-	6.5	-	7.0	—	
tw	STCP HIGH or LOW	Figure1	4.5V to 5.5V	5.5	-	-	6.0	-	6.5	-	ns
Pulse Width	SHR and STR	Figure1	3.0V to 3.6V	5.0	-	-	5.0	-	5.5	—	
	HIGH or LOW	rigurer	4.5V to 5.5V	5.0	-	-	5.2	-	5.7	—	
	DS to SHCP	Figure1	3.0V to 3.6V	3.5	-	-	3.5	-	3.5	-	ns
	DS to SITCP	rigurei	4.5V to 5.5V	3.0	-	-	3.0	-	3.0	—	115
t _{SU}	SHR to STCP	Figure1	3.0V to 3.6V	8.0	-	-	9.0	-	9.5	-	
Set-up Time	SHR to STCP	Figure i	4.5V to 5.5V	5.0	-	-	5.0	-	5.5	-	
	SHCP tp	Figure1	3.0V to 3.6V	8.0	-	-	8.5	-	9.0	-	ns
	STCP	Figure i	4.5V to 5.5V	5.0	-	-	5.0	-	5.5	-	
t _H	DS to SHCP	Figure1	3.0V to 3.6V	1.5	-	-	1.5	-	1.5	-	ns
Hold Time	D3 10 3HCF	Figure i	4.5V to 5.5V	2.0	-	-	2.0	-	2.0	-	
		Figure1	3.0V to 3.6V	4.2	-	-	4.8	-	5.3	-	20
t _{REC}	SHR to SHCP	Figure i	4.5V to 5.5V	2.9	-	-	3.3	-	3.8	-	ns
Recovery Time		Figure1	3.0V to 3.6V	4.6	-	-	5.3	-	5.8	-	20
	SHR to STCP	Figure i	4.5V to 5.5V	3.2	-	-	3.7	-	4.3	-	ns
			3.0V to 3.6V	-	5.2	8.5	2.2	9.7	2.2	10.6	
	SHCP toQ7S	Figure1 C _L = $15pF$	4.5V to 5.5V	-	3.8	6.3	1.7	7.2	1.7	7.8	
t _{PLH}	3HCF 10Q/3		3.0V to 3.6V	-	7.4	11.5	3.0	13.2	3.0	14.3	ns
LOW to HIGH		Figure1 $C_L = 50pF$	4.5V to 5.5V	-	4.8	8.0	2.4	9.1	2.4	10.0	1
Propagation			3.0V to 3.6V	-	5.1	8.3	2.3	9.5	2.3	10.6	
Delay	STCP to Qn	Figure1 C _L = $15pF$	4.5V to 5.5V	-	3.5	5.7	1.8	6.5	1.8	7.1	- ns
	SICP to QI		3.0V to 3.6V	-	7.3	11.9	3.3	13.6	3.3	14.7	
		Figure1 C _L = 50pF	4.5V to 5.5V	-	4.8	7.8	2.6	9.0	2.6	9.8	



Switching Characteristics (cont.)

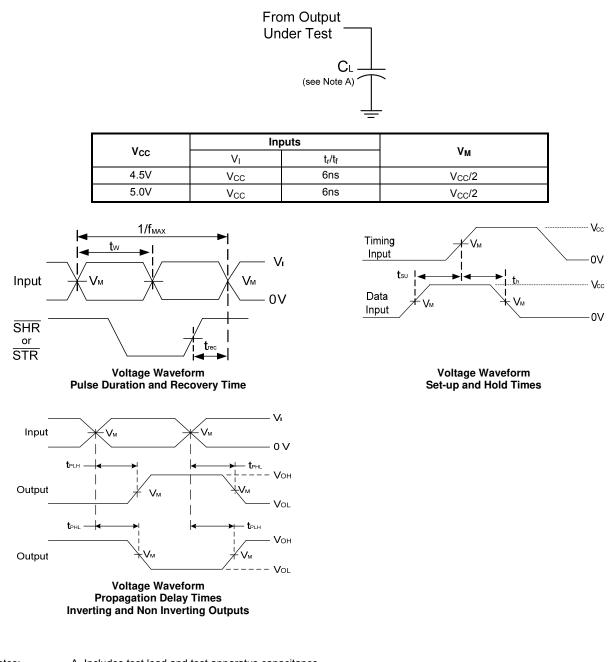
Symbol /	Dina	To sho su diti su s	V	Т		С	-40°C°C	to +85°C	-40°C°C t	to +125°C	
Parameter	Pins	Test Conditions	V _{CC}	Min	Тур	Max	Min	Max	Min	Max	Unit
		5	3.0V to 3.6V	-	5.5	8.9	2.3	10.2	2.3	11.0	
	SHCP toQ7S	Figure 1 C_L = 15pF	4.5V to 5.5V	-	4.1	6.7	1.9	7.6	1.9	8.2	
	SHUP TOU/S	Figure 4.0 50 F	3.0V to 3.6V	-	7.4	12.1	3.0	13.9	3.0	15.1	ns
		Figure 1 C_L = 50pF	4.5V to 5.5V	_	5.4	8.8	2.5	10.1	2.5	11.0	
			3.0V to 3.6V	_	5.5	9.1	2.4	10.4	2.4	11.3	
	STCP to Qn	Figure 1 C _L = 15pF	4.5V to 5.5V	-	3.7	6.0	1.9	6.9	1.9	7.5	-
tрнLн	SICPIDUI		3.0V to 3.6V	_	7.3	12.0	3.2	13.8	3.2	15.0	ns
HIGH to LOW		Figure 1 C_L = 50pF	4.5V to 5.5V	_	5.2	8.5	2.6	9.7	2.6	10.5	
Propagation		5	3.0V to 3.6V	-	5.7	9.5	2.3	10.8	2.3	11.7	
Delay	SHR to	Figure 1 C _L = 15pF	4.5V to 5.5V	-	4.1	6.7	2.0	7.6	2.0	8.2	-
	Q7S		3.0V to 3.6V	-	7.5	12.2	3.6	14.0	3.6	15.2	ns
		Figure 1 C_L = 50pF	4.5V to 5.5V	_	5.4	8.8	2.8	10.1	2.8	11.0	
			3.0V to 3.6V	_	4.1	7.2	2.2	8.2	2.2	8.9	
	STR	Figure 1 C_L = 15pF	4.5V to 5.5V	-	4.1	7.2	2.2	8.2	2.2	8.9	ns
	to Qn	Figure 1 C_L = 50pF	3.0V to 3.6V	-	5.4	9.4	3.0	10.7	3.0	11.6	
			4.5V to 5.5V	-	5.4	9.4	3.0	10.7	3.0	11.6	
			2.0V	-	39	150	-	185	-	225	ns
		Figure 1	4.5V	_	14	30	_	37	_	45	
	SHR to Q7S		5.0V	-	11	-	-	-	-	-	
t _{PHL}			6.0V	-	12	26	-	31	-	38	
Propagation Delay			2.0V	-	39	125	-	155	-	185	
Dolay		Figure 1	4.5V	-	14	25	-	31	-	37	20
	STR to Qn		5.0V	_	11	-	_	_	_	_	ns
			6.0V	-	12	21	-	26	-	31	
		Eisen d	2.0V	-	19	75	-	95	-	110	
	Serial data output Q7S	Figure 1	4.5V	-	7	15	-	19	_	22	ns
t _{THL}			6.0V	-	6	13	-	16	-	19	
Transition Time	Denallal Data	Figure 4	2.0V	-	14	60	-	75	-	90	
	Parallel Data Outputs Q _N	Figure 1	4.5V	-	5	12	-	15	-	18	ns
			6.0V	_	4	10	-	13	_	15	

Operating Characteristics (@T_A = +25°C, unless otherwise specified.)

	Parameter	Test Conditions	V _{CC} = 5V Typ	Unit
C _{pd}	Power dissipation capacitance	f = 1 MHz all outputs switching-no load	51	pF



Parameter Measurement Information



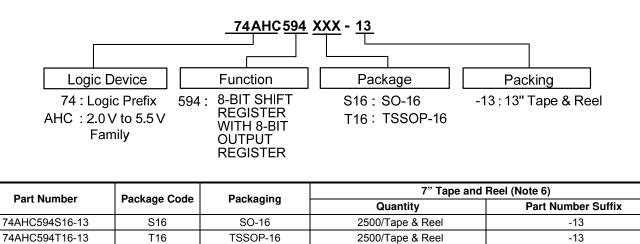
Notes:

- A. Includes test lead and test apparatus capacitance.B. All pulses are supplied at pulse repetition rate ≤ 10MHz.
- C. Inputs are measured separately one transition per measurement.
- D. t_{PLH} and t_{PHL} are the same as t_{PD} .

Figure 1 Load Circuit and Voltage Waveforms



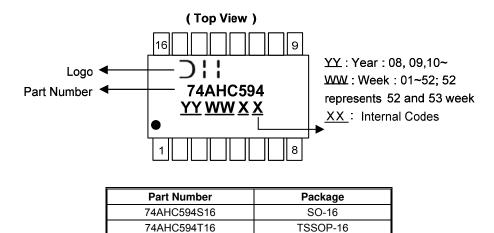
Ordering Information



Note: 6. The taping orientation is located on our website at http://www.diodes.com/datasheets/ap02007.pdf

Marking Information

(1) SO-16, TSSOP16

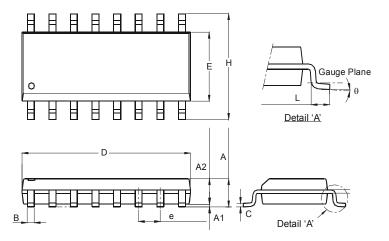




Package Outline Dimensions (All dimensions in mm.)

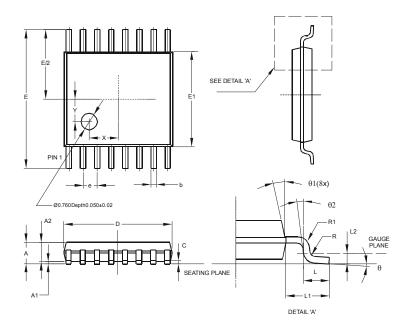
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

Package Type: SO-16



	SO-16	
Dim	Min	Max
Α	1.40	1.75
A1	0.10	0.25
A2	1.30	1.50
В	0.33	0.51
С	0.19	0.25
D	9.80	10.00
Е	3.80	4.00
е	1.27	Тур
H	5.80	6.20
L	0.38	1.27
Θ	0°	8°
All D	imension	s in mm

Package Type: TSSOP-16



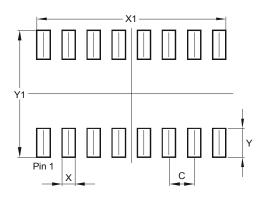
TSSOP-16							
Dim	Min	Max	Тур				
Α	-	1.08	-				
A1	0.05	0.15	-				
A2	0.80	0.93	-				
b	0.19	0.30	-				
С	0.09	0.20	-				
D	4.90	5.10	-				
Ε	6	6.40 BS	SC				
E1	4.30	4.50	-				
е	0	.65 BS	SC				
L	0.45	0.75	-				
L1	1	.00 RI	EF				
L2	0	.25 BS	SC				
R	0.09	-	-				
R1	0.09	-	-				
Х	-	-	1.350				
Y	-	-	1.050				
Θ	0°	8°	-				
Θ1	5°	15°	-				
Θ2	0°	-	-				
All D	Dimens	sions i	in mm				



Suggested Pad Layout

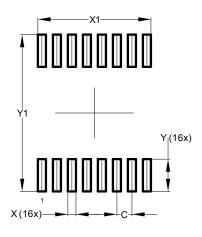
Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

Package Type: SO-16



Dimensions	Value (in mm)
С	1.270
Х	0.670
X1	9.560
Y	1.450
Y1	6.400

Package Type: TSSOP-16



Dimensions	Value (in mm)
С	0.650
Х	0.350
X1	4.900
Y	1.400
Y1	6.800



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